NSN 5961-01-315-4418

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View Online at https://aerobasegroup.com/nsn/5961-01-315-4418 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.295 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -450.0 collector to base voltage/static/emitter open and -6.0 emitter to base voltage, static, collector open and -450.0 collector to emitter voltage, dc with specified circuit between base and emitter **Current Rating Per Characteristic:** -2.00 amperes source cutoff current and -1.00 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case **Specification Data:** 80131-release 6426 professional/industrial association specification Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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